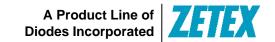
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ZXMP3F37DN8

Maximum Ratings @TA = 25°C unless otherwise specified

| Characteristic | | | Symbol | Value | Unit |
|--|------------------------|-------------------------------------|-----------------|-------|------|
| Drain-Source voltage | | | V_{DSS} | -30 | V |
| Gate-Source voltage | | V_{GS} | ±20 | V | |
| Continuous Drain current | | (Notes 3 & 5) | Ι _D | -7.3 | А |
| | V _{GS} = -10V | T _A = 70°C (Notes 3 & 5) | | -5.9 | |
| | | (Notes 2 & 5) | | -5.7 | ^ |
| | | (Note 7) | | -8.3 | |
| Pulsed Drain current (| | (Notes 4) | I _{DM} | -36 | Α |
| Continuous Source current (Body diode) (Notes 3) | | (Notes 3) | Is | -3.5 | A |
| Pulsed Source current (Body diode) (Notes 4) | | I _{SM} | -36 | А | |

Thermal Characteristics @TA = 25°C unless otherwise specified

| Characteristic | Symbol | Value | Unit | | |
|---|-----------------------------------|-----------------|--------------|------------|--|
| | (Notes 2 & 5) | | 1.25 10.0 | | |
| Power dissipation | (Notes 2 & 6) | | 1.81 14 | W mW/°C | |
| Linear derating factor | (Notes 3 & 5) | P _D | 2.1 17 | | |
| | (Notes 2 & 7) | | 2.7 22 | | |
| | (Notes 2 & 5) | | 100 | | |
| Thermal Resistance, Junction to Ambient | (Notes 2 & 6) | $R_{\theta JA}$ | 70 | 20.044 | |
| | (Notes 3 & 5) | 7 | 60 | °C/W | |
| Thermal Resistance, Junction to Lead | (Notes 2 & 7) | $R_{	heta JL}$ | 46 | | |
| Operating and storage temperature range | T _J , T _{STG} | -55 to +150 | °C | | |

Notes:

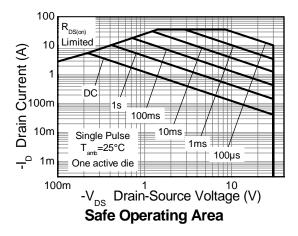
- For a device surface mounted on 25mm x 25mm x 1.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions; the device is measured when operating in a steady-state condition.
 For a dual device surface mounted on FR4 PCB measured at t ≤ 10 sec.
 Repetitive rating on 25mm X 25mm FR4 PCB, pulsed with D = 0.02 and pulse width 300µs pulse width limited by maximum junction temperature.

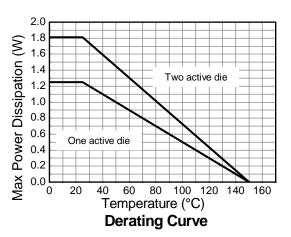
- 5. For a dual device with one active die.
- 6. For a device with two active die running at equal power.
- 7. Thermal resistance from junction to solder-point (at the end of the drain lead).

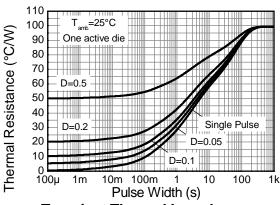


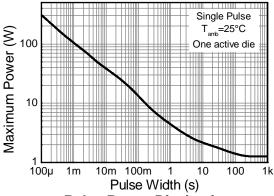


Thermal Characteristics









Transient Thermal Impedance

Pulse Power Dissipation

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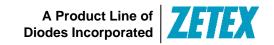
Electrical Characteristics @T_A = 25°C unless otherwise specified

| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition | |
|--|----------------------|------|------|------|------|---|--|
| OFF CHARACTERISTICS | | | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | -30 | | | V | $I_D = -250 \mu A$, $V_{GS} = 0 V$ | |
| Zero Gate Voltage Drain Current | I _{DSS} | _ | | -0.5 | μΑ | $V_{DS} = -30V, V_{GS} = 0V$ | |
| Gate-Source Leakage | I _{GSS} | _ | _ | ±100 | nA | $V_{GS} = \pm 20V, V_{DS} = 0V$ | |
| ON CHARACTERISTICS | | | | | | | |
| Gate Threshold Voltage | V _{GS(th)} | -1.0 | | -3.0 | ٧ | $I_D = -250 \mu A$, $V_{DS} = V_{GS}$ | |
| Static Drain-Source On-Resistance (Note 8) | D | | _ | 25 | mΩ | $V_{GS} = -10V, I_D = -7.1A$ | |
| Static Drain-Source On-Resistance (Note 8) | R _{DS} (ON) | _ | _ | 41 | | $V_{GS} = -4.5V$, $I_D = -5.5A$ | |
| Forward Transconductance (Notes 8 & 9) | g _{fs} | _ | 18.6 | | S | $V_{DS} = -15V$, $I_{D} = -7.1A$ | |
| Diode Forward Voltage (Note 8) | V_{SD} | _ | -0.8 | -1.2 | V | $I_S = -1.7A$, $V_{GS} = 0V$ | |
| Reverse recovery time (Note 9) | t _{rr} | | 16.2 | _ | ns | 1 2 2 A di/dt 100 A / | |
| Reverse recovery charge (Note 9) | Q_{rr} | _ | 10 | _ | nC | $I_S = -2.2A$, di/dt = 100A/ μ s | |
| DYNAMIC CHARACTERISTICS (Note 9) | , , , | | | | | | |
| Input Capacitance | C _{iss} | _ | 1678 | | рF | | |
| Output Capacitance | Coss | _ | 303 | _ | pF | V _{DS} = -15V, V _{GS} = 0V -f = 1MHz | |
| Reverse Transfer Capacitance | C _{rss} | _ | 178 | _ | pF | | |
| Total Gate Charge (Note 10) | Q_g | _ | 31.6 | _ | nC | 10)/)/ 15)/ | |
| Gate-Source Charge (Note 10) | Q_{gs} | _ | 4.3 | _ | nC | $V_{GS} = -10V, V_{DS} = -15V,$ | |
| Gate-Drain Charge (Note 10) | Q_{gd} | _ | 6.2 | _ | nC | I _D = -7.1A | |
| Turn-On Delay Time (Note 10) | t _{D(on)} | _ | 3.5 | _ | ns | | |
| Turn-On Rise Time (Note 10) | t _r | _ | 4.9 | _ | ns | V _{DD} = -15V, V _{GS} = -10V | |
| Turn-Off Delay Time (Note 10) | t _{D(off)} | _ | 44 | _ | ns | $I_D = -1A, R_G \cong 6.0\Omega$ | |
| Turn-Off Fall Time (Note 10) | t _f | _ | 28 | | ns | | |

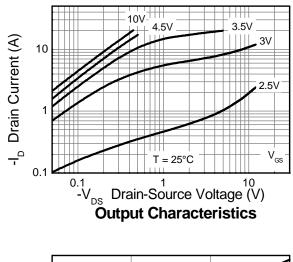
Notes:

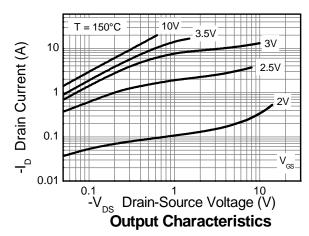
- 8. Measured under pulsed conditions. Pulse width $\leq 300 \mu s;$ duty cycle $\leq 2\%$
- For design aid only, not subject to production testing.
 Switching characteristics are independent of operating junction temperatures.

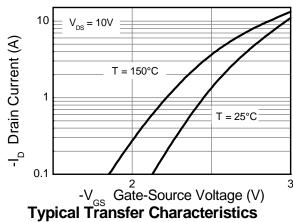


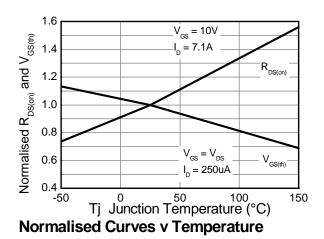


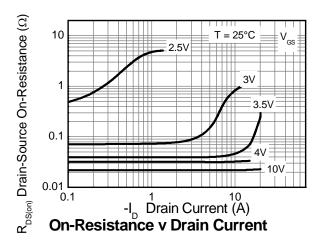
Typical Characteristics

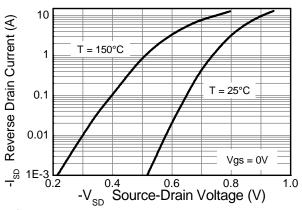






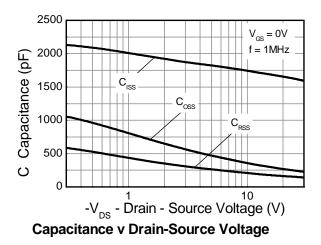


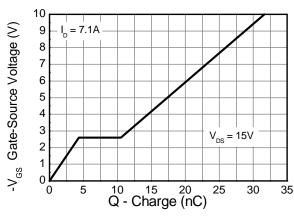






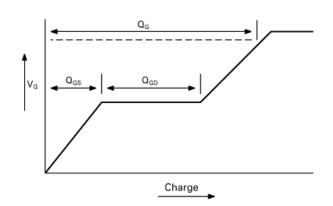
Typical Characteristics - continued





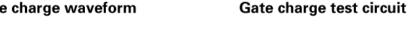
Gate-Source Voltage v Gate Charge

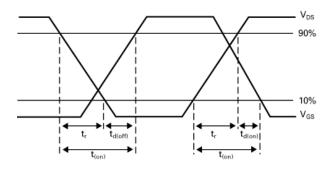
Test Circuits

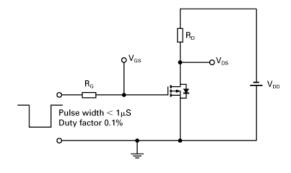


Current regulator Ј**Б**⊋р.∪.т

Basic gate charge waveform



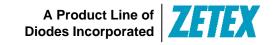




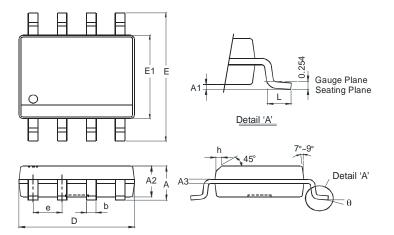
Switching time waveforms

Switching time test circuit



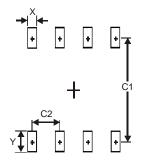


Package Outline Dimensions



| SO-8 | | | | |
|----------------------|----------|------|--|--|
| Dim | Min | Max | | |
| Α | - | 1.75 | | |
| A1 | 0.10 | 0.20 | | |
| A2 | 1.30 | 1.50 | | |
| A3 | 0.15 | 0.25 | | |
| b | 0.3 | 0.5 | | |
| D | 4.85 | 4.95 | | |
| E | 5.90 | 6.10 | | |
| E1 | 3.85 | 3.95 | | |
| е | 1.27 Typ | | | |
| h | - | 0.35 | | |
| L | 0.62 | 0.82 | | |
| θ | 0° | 8° | | |
| All Dimensions in mm | | | | |

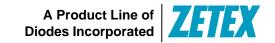
Suggested Pad Layout



| Dimensions | Value (in mm) |
|------------|---------------|
| X | 0.60 |
| Y | 1.55 |
| C1 | 5.4 |
| C2 | 1.27 |

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